

# DATASHEET

ERZ-HPA-2000-4000-39-NS

# ERZIA



## NEW SPACE

High Power Amplifiers

20 to 40 GHz

Gain 52 dB, Psat 39 dBm

### Description:

The ERZ-HPA-2000-4000-39-NS is a microwave power amplifier based on GaN, specially prepared for New Space applications. It is based on its commercial grade equivalent, maintaining electrical performance and including key features ideal for new space applications, including radiation tolerance, performance in vacuum and outgassing compatibility, among others. See table next page.

### Key Technical Features:

- Frequency Range: 20 to 40 GHz.
- Typical values: Gain 52 dB, Psat 39 dBm
- RF connectors (I/O): 2.92 mm (F)
- MicroSub-D for control and DC connection

### Electrical Performance

Parameter	Value			Units
	Min	Typ	Max	
Frequency	20	-	40	GHz
Output Power (Psat)	37.5	39	41	dBm
Small Signal Gain	47	52	57	dB
Gain Flatness	-	±2.5	-	dB
VSWR input	-	2.0:1	2.5:1	-
VSWR output	-	2.0:1	3.0:1	-
DC Voltage	24	28	32	V
Power Consumption @PSat	-	95	-	W
RF Connectors	2.92 mm (F) IN/ OUT			-

Specifications at case temperatura of 25°C.

### New Space (-NS) versions

Feature	COTS	NEW Space (-NS)
Operating Temperature range -45 to +85 °C (MIL-STD-810F, method 520.2)	x	x
Random Vibration 8g RMS (MIL-STD-810F, method 514.5)	x	x
Mechanical Shock 20g, 11ms SawTooth (MIL-STD-810F, method 516.5)	x	x
Acceleration 15g (MIL-STD-810F, method 513.5)	x	x
Thermal cycling (Based in MIL-HDBK-2164 Rev. A)	x	x
Simplified power interface Single DC supply line	x	x
ATP at three temperatures CoC & CoO supplied	x	x
RF section radiation tolerance (TID) Technology intrinsically tolerant to 300 krad (TID)	x	x
RF section radiation SEE tolerance: SEE-aware RF design and filtering	-	x
DC section radiation tolerance (TID) Radiation Tolerant to 30 krad (TID) plus housing shielding.	-	x
DC section radiation SEE tolerance: Passive SEE mitigation plus rad-tolerant (43 MeV-cm <sup>2</sup> /mg) in key components	-	x
Vacuum-optimized mechanics (venting, joints) (ECSS-Q-ST-70-02)	-	x
Low-outgassing materials (ECSS-Q-ST-70 / NASA-ASTM-E595 compliant)	-	x
Pure-tin mitigation(whisker control / alternative finishes) (GEIA-STD-0005-2 guidelines)	-	x
Prepared for LEO (atomic-oxygen mitigation techniques)	-	x
Screening /of RF active devices / Complete burn in	-	<b>Optional</b>
Additional documentation & analyses (FMECA, Worst-Case, etc.) — NDA required	-	<b>Optional</b>
Environmental testing on demand (TVAC, vibration, ...)	-	<b>Optional</b>

### Output Power

Figure 1 shows output power at saturation measurement as a function of frequency at different temperatures.

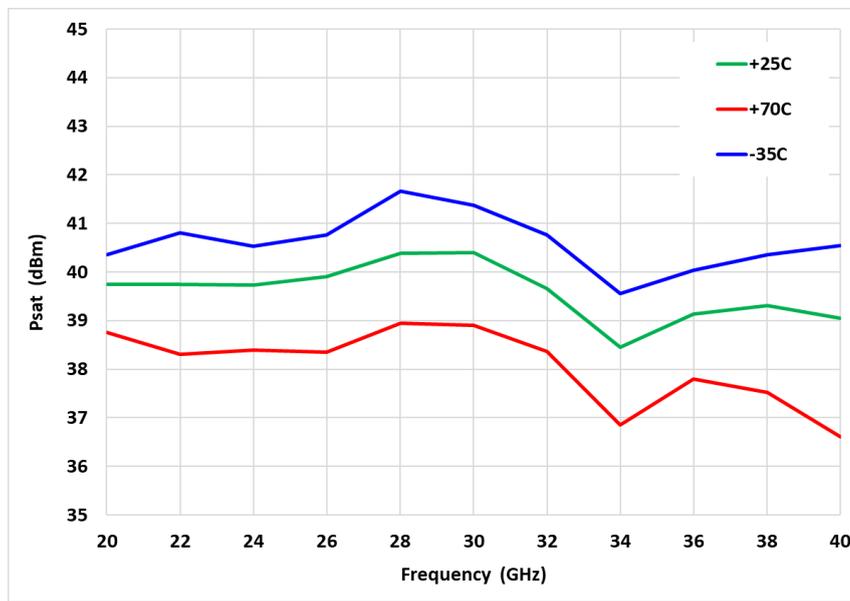


Figure 1: ERZ-HPA-2000-4000-39-NS Psat

### Small Signal Gain

Figure 2 shows the small signal gain measurement as a function of frequency at different temperatures.

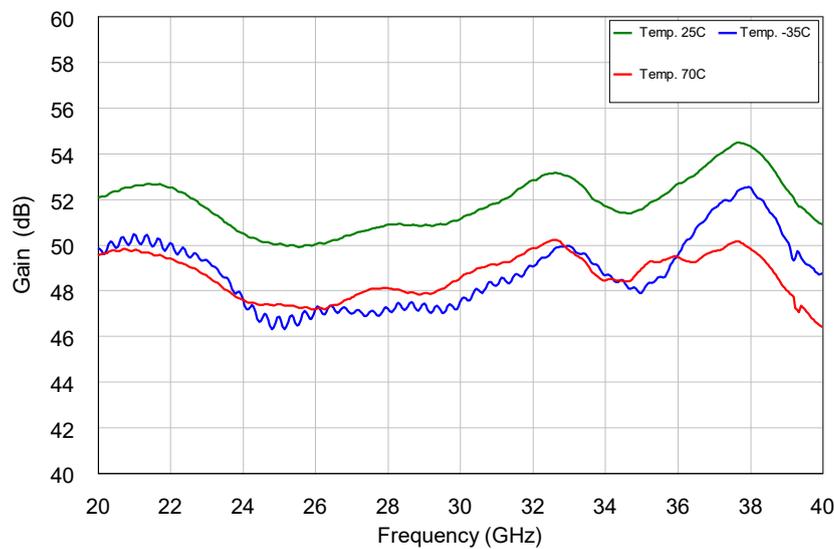


Figure 2: ERZ-HPA-2000-4000-39-NS Small Signal Gain

### Input and Output Matching

Figure 3 shows input (S11) and output (S22) VSWR as a function of frequency at room temperature (25°C).

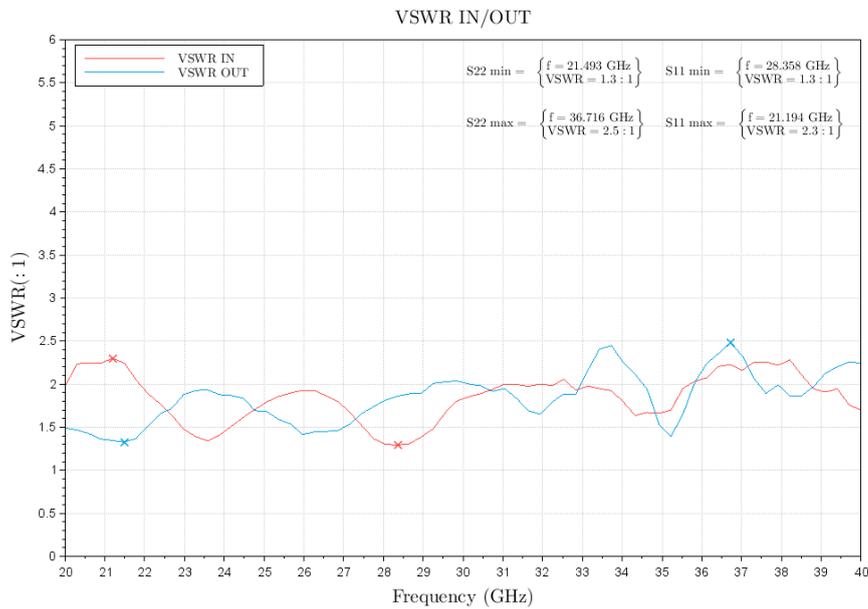


Figure 3: ERZ-HPA-2000-4000-39-NS Input & Output Matching

### Absolute Maximum Ratings

Condition	Value
DC Voltage	+32 VDC
Maximum Input Power (CW)	+15 dBm
Operation temperature (at case)	-40 to 85 °C
Storage temperature	-55 to 125 °C

- Stress above these ratings may cause permanent damage to the device.
- It is final user responsibility to maintain the amplifier within the specified ranges.

### Measurements Conditions

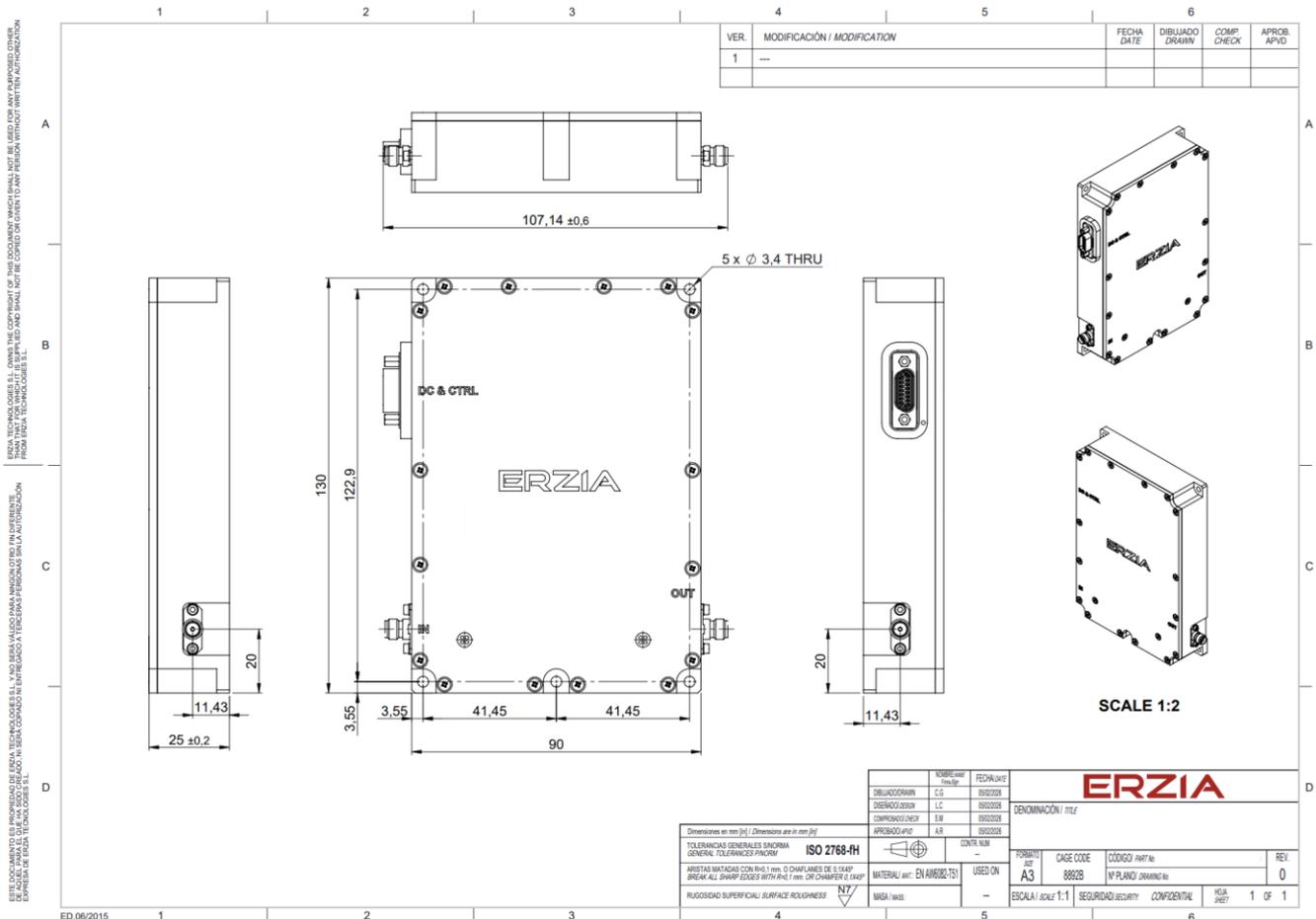
All measurements provided in this report were performed at the following conditions:

Condition	Value
Temperature (DUT ON)	25 °C ± 1°C
Humidity	44% ± 10%
DUT Warm up time	30 min
DUT minimum operation time	24 hours
Test equipment warm up time	2 hours
Additional temperature cycles in climatic chamber (DUT OFF)	-40°C to 85°C

### Environmental Specifications (By Design)

Operating Temperature:	-45 to +85 °C	(MIL-STD-810F, method 520.2)
Storage Temperature:	-55 to 125 °C	(MIL-STD-810F, method 520.2)
Vibration:	8g rms	(MIL-STD-810F, method 514.5)
Shock:	20g, 11ms, saw-tooth	(MIL-STD-810F, method 516.5)
Acceleration:	15g	(MIL-STD-810F, method 513.5)
Radiation	30 Krad, SEE mitigated	(DC section)
	300 Krad, SEE mitigated	(RF section. By Technology)
Pressure	Sea level to Vacuum	

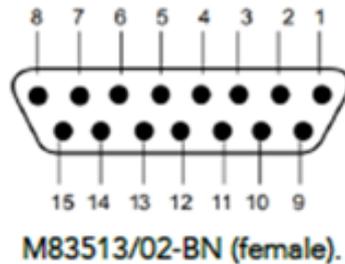
### Mechanics and Housing



Parameter	Value	Units
Dimensions	90x130x25 (LxWxH)	mm
RF Connectors	IN/OUT: 2.92mm (f)	-
DC & Control Connector	MICRO-D-sub 15 female	-

### DC and Control Connector

Micro-D Sub-15 female connector



Pin No	Function	Description
1	+28 VDC	+(24...32) VDC
2	+28 VDC	+(24...32) VDC
3	Power Ground	Power Ground
4	Power Ground	Power Ground
5	Ground	Ground
6	Current Monitor	$V_o = 0.1V/A$
7	Temperature Monitor	NTC 10K NTCG163JX103DTDS
8	Temperature Monitor Return	
9	+28 VDC	+(24...32) VDC
10	+28 VDC	+(24...32) VDC
11	Power Ground	Power Ground
12	Power Ground	Power Ground
13	Ground	Ground
14	TTL Enable	OFF (0V to 0.8V); ON (2V to 5.5V)
15	TTL Modulation	OFF (0V to 0.8V); ON (2V to 5.5V)

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